AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

- 1. 37. (Canceled)
- 38. (Previously presented) The method of claim 42 wherein the rounded corner is at an intersection of a wall of the trench and a base of the trench.
- 39. (Previously presented) The method of claim 42 wherein the rounded corner is at an intersection of a wall of the trench and a surface intersecting the wall, the surface extending generally at right angles to the wall.
- 40. (Previously presented) The method of claim 42 wherein the gradual change includes steps having power changes no greater than about several watts.
- 41. (Previously presented) The method of claim 40 wherein the power steps are a few milliwatts and remain at a constant power for about 1 millisecond.
- 42. (Currently amended) A method of forming a rounded corner of a trench of a workpiece in a vacuum plasma chamber, comprising converting a gas species that is

supplied to the chamber into an etchant plasma that is continuously applied to the workpiece while the rounded corner is being formed, gradually changing the power applied to the etchant plasma while the rounded corner is being formed, the gradual changes being such that the power does not remain constant for durations in excess of one second while the rounded corner is being formed, and, while the rounded corner is being formed, maintaining constant: (a) pressure in the chamber, (b) the flow rate of the gas species into the chamber and [[c]](b) the species flowing into the chamber.

- 43. (Previously Presented) The method of claim 42, wherein the etchant gas is the dominant gas.
- (Previously Presented) The method of claim 41, wherein the etchant gas is the dominant gas.
- 45. (New) The method of claim 42 wherein pressure in the chamber is maintained constant while the rounded corner is being formed.
- 46. (New) The method of claim 40 wherein an electric source having a maximum output power applies the gradually changing power to the etchant plasma, the steps having a maximum change of less than 5% of the source maximum output power.

- 47. (New) A method of etching a workpiece in a vacuum plasma processor chamber comprising converting a gas species into an AC etchant plasma that is applied to the workpiece while a desired shape of the workpiece is being formed, the AC etchant plasma always being the dominant material applied to the workpiece while the desired shape is being formed, the vacuum chamber being subject to operating at different pressures while the workpiece is being processed, the gas species being subject to flowing into the chamber at different flow rates while the workpiece is being processed, gradually changing, on a pre-programmed basis, the amount of AC power supplied to the plasma during etching of the workpiece to form the desired shape, wherein a gradual transition in the shape of material that has the desired shape in the workpiece being processed occurs in response to the gradual power change, the gradual power change occurring during the gradual transition in the shape of the material that has the desired shape.
- 48. (New) The method of claim 47 wherein the etchant plasma is continuously applied to the workpiece while the desired shape is being formed.
- 49. (New) The method of claim 48 wherein the gradual power change occurs while no change is made in (a) the species, (b) the pressure or (c) the flow rate.
- 50. (New)The method of claim 48 wherein the species is ionized into a plasma that etches the material to form the desired shape, the gradual power change,

the species and the continuous application of the plasma to the workpiece being such that the material is shaped to have a curved surface, the curved surface being formed in response to changes in the ionized plasma etchant resulting from the gradual power change.

- 51. (New) The method of claim 50 wherein the curved surface is a rounded corner, and the etching, which occurs in response to changes in the ionized plasma etchant resulting from the gradual power change and the continuous application of the plasma to the workpiece, forms a trench wall including the rounded corner, the trench and the rounded corner being included in the desired shape.
- (New) The method of claim 51 wherein the rounded corner is at an intersection of a wall and a base of a trench.
- 53. (New) The method of claim 50 wherein the curved surface is a rounded corner at an intersection of a wall and a surface intersecting the wall, the surface extending generally at right angles to the wall.
- 54. (New) The method of claim 49 wherein the gradual change includes steps having power changes no greater than about several watts, the power remaining at a constant wattage for no more than about 1 second.

- 55. (New) The method of claim 54 wherein the power steps are a few milliwatts and remain at a constant power for about 1 millisecond.
- 56. (New) The method of claim 54 wherein an electric source having a maximum output power applies the gradually changing power to the etchant plasma, the steps having a maximum change of less than 5% of the source maximum output power.
- 57. (New) The method of claim 48 wherein the gradual power change includes steps having power changes in the range of a few milliwatts to several watts and durations in the range of about one millisecond to no more than one second.
- 58. (New) The method of claim 50 wherein the gradual change includes steps having power changes no greater than about several watts, the power remaining at a constant wattage for no more than about 1 second.
- 59. (New) A memory storing a computer program for controlling a computer for controlling etching of a workpiece in a vacuum plasma processor chamber wherein a gas species is converted into an AC etchant plasma, the chamber being capable of operating at different pressures while the workpiece is being processed, the gas species being subject to flowing into the chamber at different flow rates while the workpiece is being processed, the computer program storing signals causing (a) control of the amount of AC power applied to the plasma while the workpiece is being etched; (b) the

application of the AC etchant plasma to the workpiece while a desired shape of the workpiece is being formed, and (c) the AC etchant plasma to always be the dominant material applied to the workpiece while the desired shape is being formed, the stored signal for controlling the amount of applied AC power causing gradual preprogrammed changes in the amount of AC power supplied to the etchant plasma during etching of the workpiece, the stored signal causing the gradual power change being such as to cause a gradual transition in the shape of material in the workpiece being etched in response to the gradual power change to cause the gradual power change to occur during the gradual transition in the shape of the material.

- 60. (New) The memory of claim 59 wherein the computer program causes the etchant plasma to be continuously applied to the workpiece while the desired shape is being formed.
- 61. (New) The memory of claim 60 wherein the computer program also stores signals for causing (a) the vacuum chamber to operate at different pressures while the workpiece is being etched and (b) control of the gas species type and the flow rates thereof into the chamber while the workpiece is being etched, the stored signals causing the gradual power change to occur while no change is made in (a) the species, (b) the pressure or (c) the flow rate.

- 62. (New) The memory of claim 60 wherein the stored signals control (a) etchant species supplied to the chamber while the workpiece is being processed and (b) the gradual power transition so as to cause the workpiece to be etched so the desired shape is a curved surface.
- 63. (New) The memory of claim 62 wherein the curved surface is a rounded corner, and the stored signals control (a) etchant species supplied to the chamber while the workpiece is being processed and (b) the gradual power transition so as to cause the workpiece to be etched to have a trench wall including the rounded corner.
- 64. (New) The memory of claim 63 wherein the rounded corner is at an intersection of a wall and a base of a trench.
- 65. (New) The memory of claim 62 wherein the gradual change includes steps having power changes in the range of a few milliwatts to several watts and having durations in the range of about one millisecond to no more than one second.
- 66. (New) The memory of claim 60 wherein the gradual change includes steps having power changes in the range of a few milliwatts to several watts and having durations in the range of about one millisecond to no more than one second.